THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of: FUKASAWA, et al.

Group Art Unit: 2814

Serial No.: 09/029,608

Examiner: D. Graybill

Filed: May 15, 1998

P.T.O. Confirmation No.: 6285

For.

METHOD AND MOLD FOR MANUFACTURING SEMICONDUCTOR DEVICE,

SEMICONDUCTOR

<u>AMENDMENT</u>

Commissioner for Patents P.O. Box 1450 Alexandria, Va 22313-1450

Date: May 6, 2003

Sir:

Prior to continued examination, please amend the above-captioned patent application as follows:

IN THE CLAIMS:

Please amend claims 109-111, 115, 119, 129 and 132 as follows:

(Three Times Amended) A semiconductor device comprising: 109.

a semiconductor element having a surface on which protruding electrodes are formed;

a resin layer formed on the surface of the semiconductor element so as to seal the protruding electrodes except end portions thereof, said end portions protruding a height from the resin layer; and external connection protruding electrodes provided to the end portions of the protruding